

UNISONIC TECHNOLOGIES CO., LTD

CD4069 **CMOS IC**

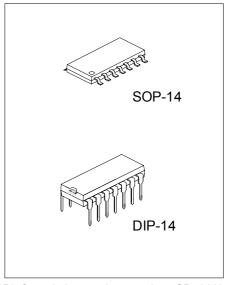
INVERTER CIRCUIT

DESCRIPTION

The UTC CD4069 is a CMOS IC with six inverter circuits and designed for using of wide power supply operating range, low power consumption, high noise immunity, and symmetric controlled rise and fall times. The IC is capable of ESD protection by diode clamps to VDD and VSS.

FEATURES

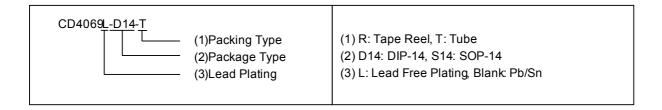
- * Wide supply voltage range: 3.0V ~ 15V.
- * High noise immunity: $0.45 V_{DD}$ typ.
- * Low Power TTL compatibility: Fan out of 2 driving 74L or 1 driving 74LS.



*Pb-free plating product number: CD4069L

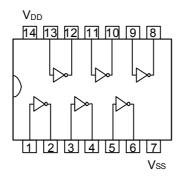
ORDERING INFORMATION

Order Number		Dookaga	Dooking	
Normal	Lead Free Plating	Package	Packing	
CD4069-D14-T	CD4069L-D14-T	DIP-14	Tube	
CD4069-S14-R	CD4069L-S14-R	SOP-14	Tape Reel	
CD4069-S14-T	CD4069L-S14-T	SOP-14	Tube	

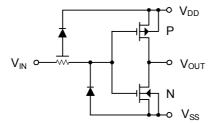


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■ PIN CONFIGURATION



■ BLOCK DIAGRAM



■ ABSOLUTE MAXIMUM RATINGS

PARAMETER		SYMBOL	RATINGS	UNIT
DC Supply Voltage		V_{DD}	-0.5 ~ +18	V
Input Voltage		V_{IN}	-0.5 ~ V _{DD} +0.5	V
Storage Temperature Range		Ts	-65 ~ +150	
Dower Dissipation	DIP-14	ь	700	mW
Power Dissipation	SOP-14	P _D	500	mW
Junction Temperature		TJ	125	
Operating Temperature		T _{OPR}	-20 ~ +85	
Storage Temperature		T _{STG}	-40 ~ + 150	

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ RECOMMENDED OPERATING CONDITIONS (V_{SS}=0V)

PARAMETER	SYMBOL	RATINGS	UNIT
DC Supply Voltage	V_{DD}	3 ~ 15	V
Input Voltage	V_{IN}	0 ~ V _{DD}	V
Operating Temperature Range	Та	-40 ~ +85	

■ DC ELECTRICAL CHARACTERISTICS (V_{SS}=0V, Ta=25 , unless otherwise specified.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Quiescent Device Current	I _{DD}	V_{DD} =5V, V_{IN} = V_{DD} or V_{SS} V_{DD} =10V, V_{IN} = V_{DD} or V_{SS} V_{DD} =15V, V_{IN} = V_{DD} or V_{SS}			1.0 2.0 4.0	μΑ
Low Level Output Voltage	V _{OL}	I _O <1µA V _{DD} =5V V _{DD} =10V V _{DD} =15V		0 0 0	0.05 0.05 0.05	V
High Level Output Voltage	V _{он}	I _O <1µA V _{DD} =5V V _{DD} =10V V _{DD} =15V	4.95 9.95 14.95			V
Low Level Input Voltage	V _{IL}	I _O <1µA V _{DD} =5V, V _{OUT} =4.5V V _{DD} =10V, V _{OUT} =9V V _{DD} =15V, V _{OUT} =13.5V			1.0 2.0 3.0	V
High Level Input Voltage	V _{IH}	$ I_{O} <1\mu A$ $V_{DD}=5V$, $V_{OUT}=0.5V$ $V_{DD}=10V$, $V_{OUT}=1V$ $V_{DD}=15V$, $V_{OUT}=1.5V$	4.0 8.0 12.0			V
Low Level Output Current (Note 3)	l _{OL}	V _{DD} =5V, V _{OUT} =0.4V V _{DD} =10V, V _{OUT} =0.5V V _{DD} =15V, V _{OUT} =1.5V	0.44 1.1 3.0	0.88 2.25 8.8		mA
High Level Output Current (Note 3)	Іон	V _{DD} =5V, V _{OUT} =4.6V V _{DD} =10V, V _{OUT} =9.5V V _{DD} =15V, V _{OUT} =13.5V	-0.44 -1.1 -3.0	-0.88 -2.25 -8.8		mA
Input Current	I _{IN}	V _{DD} =15V, V _{IN} =0V V _{DD} =15, V _{IN} =15V		-10 ⁻⁵	-0.30 0.30	μA

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■ AC ELECTRICAL CHARACTERISTICS(Note 1)

(Ta=25 , C_L=50pF, R_L=200k Ω , t_r and t_f ≤ 20 ns, unless otherwise specified)

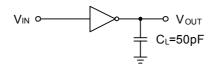
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Propagation Delay Time from Input to Output	t _{PHL} or t _{PLH}	V _{DD} =5V		50	90	
		V _{DD} =10V		30	60	ns
		V _{DD} =15V		25	50	
Transition Time	t_{THL} or t_{TLH}	V _{DD} =5V		80	150	
		V _{DD} =10V		50	100	ns
		V _{DD} =15V		40	80	
Average Input Capacitance	C _{IN}	Any Gate		6	15	pF
Power Dissipation Capacitance	C_PD	Any Gate (Note 3)		12		pF

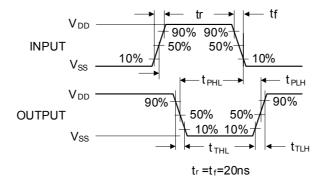
Note: 1.AC Parameters are guaranteed by DC correlated testing.

^{2:} I_{OH} and I_{OL} are tested one output at a time.

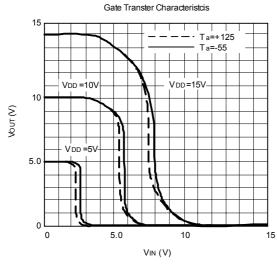
^{3:} C_{PD} determines the no load AC power consumption of any CMOS device.

■ AC TEST CIRCUITS AND SWITCHING TIME WAVEFORMS

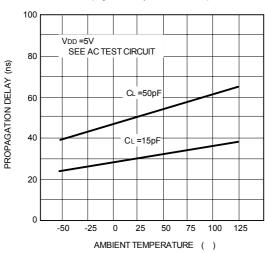




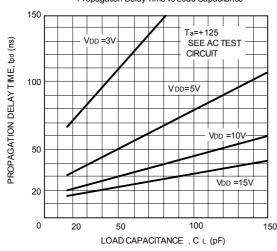
■ TYPICAL CHARACTERISTICS



Propagation Delay vs Ambient Temperature

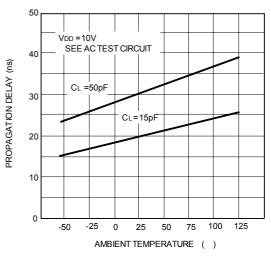


Propagation Delay Time vs Load Capacitance



Power Dissipation vs Frequency 10⁵ POWER DISSIPATION FOR POWER DISSIPATION PER GATE (µW) OTHER DEVICES IS GIVEN BY PD=(CL+CPD)(VDD)² 10⁴ ----CL=50pF VDD =10V CL =15pF 10³ VDD =10V VDD =5V 102 CL =50pF V DD =5V 10 10³ 10⁵ 10⁷ 104 INPUT FREQUENCY (Hz)

Propagation Delay vs Ambient Temperature



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